TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SH14FE

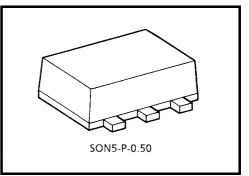
SCHMITT INVERTER

Features

• Super high speed operation :tpD = 5.5 ns (typ.)

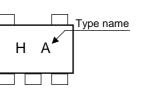
 $@V_{CC} = 5 V$

- Low power dissipation : $I_{CC} = 2 \ \mu A$ (Max.) @ Ta = 25°C
- 5.5V tolerant input.
- Wide operation voltage range : V_{CC} (opr) = 2~5.5 V

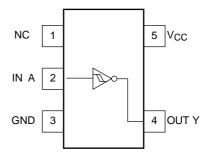


Weight: 0.003 g (typ.)

Marking



Pin Assignment (top view)

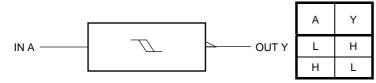


Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~7	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	IOK	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T _{stg}	-65~150	°C

<u>TOSHIBA</u>

Logic Diagram



Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2~5.5	V
Input voltage	V _{IN}	0~5.5	V
Output voltage	V _{OUT}	0~ V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	dt/dv	0~100 (V_{CC} = 3.3 V \pm 0.3 V)	ns/V
	u/uv	0~20 (V_{CC} = 5 V \pm 0.5 V)	113/ V

Truth Table

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Track Operativity			Ta = 25°C			Ta = -40~85°C		Linit
Characteristics Symbol		Test Condition		V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
Positive Threshold Voltage		—		3.0			2.20		2.20	V
	VP			4.5	_	_	3.15	—	3.15	
				5.5		_	3.85		3.85	
Negative Threshold Voltage		_		3.0	0.90		_	0.90		V
	V _N			4.5	1.35			1.35		
				5.5	1.65			1.65		
Hysteresis Voltage		_		3.0	0.30		1.20	0.30	1.20	V
	V_{H}			4.5	0.40		1.40	0.40	1.40	
				5.5	0.50		1.60	0.50	1.60	
	V _{OH}	V _{IN} = V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	—	1.9	_	V
				3.0	2.9	3.0		2.9		
High-level output voltage				4.5	4.4	4.5	—	4.4	—	
			I _{OH} = -4 mA	3.0	2.58		—	2.48	—	
			I _{OH} = -8 mA	4.5	3.94		—	3.80	—	
Low-level output voltage		VIN = VIH	I _{OL} = 50 μA	2.0	—	0	0.1	—	0.1	V
				3.0	—	0	0.1	—	0.1	
	V _{OL}			4.5	—	0	0.1	—	0.1	
			$I_{OL} = 4 \text{ mA}$	3.0	_		0.36	—	0.44	
			I _{OL} = 8 mA	4.5	—		0.36	—	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5	_		±0.1	_	±1.0	μA
Quiescent supply current	ICC	$V_{IN} = V_{CC}$ or GND		5.5	_		2.0		20.0	μA

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40~85°C		Unit
			V _{CC} (V)	C _{L (} pF)	Min	Тур.	Max	Min	Max	Unit
Propagation delay time	tplh tphl		3.3 ± 0.3	15		8.3	12.8	1.0	15.0	- ns
				50		10.8	16.3	1.0	18.5	
			5.0 ± 0.5	15		5.5	8.6	1.0	10.0	
				50		7.0	10.6	1.0	12.0	
Input capacitance	C _{IN}					4	10		10	pF
Power dissipation capacitance	C _{PD}	(Note)			_	14				pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation.

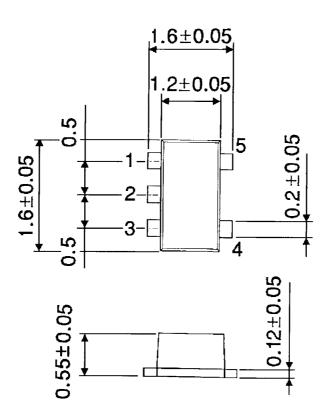
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

TOSHIBA

Package Dimensions

SON5-P-0.50

Unit : mm



Weight: 0.003 g (typ.)

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Handbook" etc..

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